TOSHIBA Field Effect Transistor Silicon N Channel MOS Type

# 2SK3656

## VHF- and UHF-band Amplifier Applications

• Output power: Po =28.4dBmW (typ)

• Gain: Gp = 15.4dB (typ)

• Drain efficiency:  $\eta_D = 64\%$  (typ)

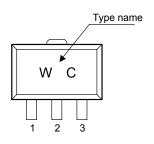
## Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Drain-source voltage	$V_{DSS}$	7.5	V
Gain-source voltage	V <sub>GSS</sub> (Note 1)	3.5	V
Drain current	I <sub>D</sub>	0.5	Α
Power dissipation	P <sub>D</sub> (Note 2)	3	W
Channel temperature	T <sub>ch</sub>	150	°C
Storage temperature range	T <sub>stg</sub>	-45~150	°C

Note 1: Recommended Opelation Condition: 0~3.5V

Note 2: Tc = 25°C (When mounted on a 1.6 mm glass epoxy PCB)

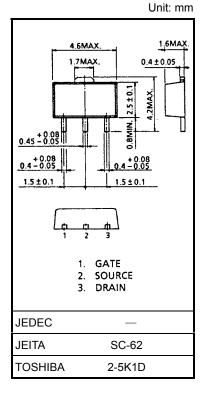
# Marking



- 1. Gate
- 2. Source
- 3. Drain

#### Caution

Please take care to avoid generating static electricity when handling this transistor.



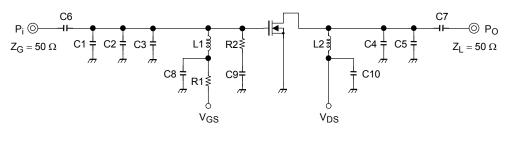
## **Electrical Characteristics (Ta = 25°C)**

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Output power	PO	$V_{DS} = 3.6 \text{ V},$ $I_{idle} = 50 \text{ mA} \text{ (V}_{GS} = \text{adjust}),$	27.5	28.4	_	dBmW
Drain efficiency	$\eta_{D}$		50	64	_	%
Power gain	G <sub>P</sub>	$f = 470 \text{ MHz}, P_i = 13 \text{dBmW},$	_	15.4	_	dB
Threshold voltage	$V_{th}$	$V_{DS} = 3.6 \text{ V}, I_D = 0.5 \text{ mA}$	0.2	_	1.2	V
Drain cut-off current	I <sub>DSS</sub>	$V_{DS} = 7.5 \text{ V}, V_{GS} = 0 \text{ V}$	_	_	10	μА
Gate-source leakage current	I <sub>GSS</sub>	$V_{GS} = 3.5 \text{ V}, V_{DS} = 0 \text{ V}$	_	_	5	μА
Load Mismatch (Note 3)		$\begin{split} &V_{DS}=3.6~\text{V, f}=470~\text{MHz,}\\ &P_i=13\text{dBmW,}\\ &P_0=27\text{dBmW (V}_{GS}=\text{adjust),}\\ &\text{VSWR LOAD 10:1 all phase} \end{split}$	No Degradation		_	

Note 3: These characteristic values are measured using measurement tools specified by Toshiba.

#### **Output Power Test Fixture**

(Test Condition: f = 470 MHz,  $V_{DS} = 3.6 \text{ V}$ ,  $I_{idle} = 50 \text{ mA}$ ,  $P_i = 13 \text{ dBmW}$ )



C1: 7 pF

C2: 10 pF

L1:  $\phi$ 0.6 mm enamel wire, 5.5ID, 5T L2:  $\phi$ 0.6 mm enamel wire, 5.5ID, 7T

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R1:  $6.8 \text{ k}\Omega$ R2: 56  $\Omega$ 

C3: 5 pF

C4: 13 pF

C5: 8 pF

C6: 2200 pF

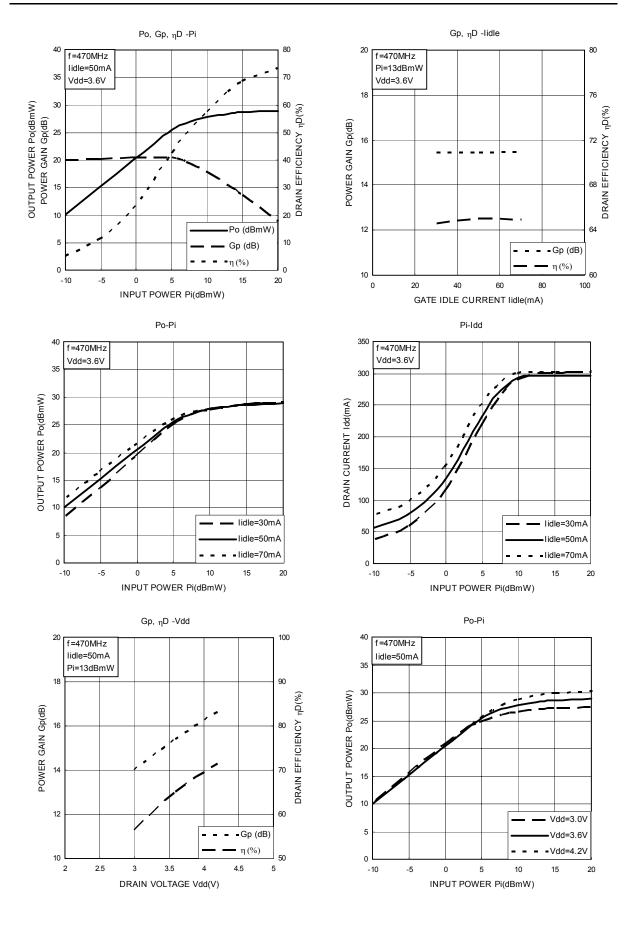
C7: 2200 pF

C8: 10000 pF

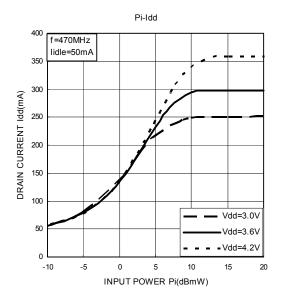
C9: 2200 pF

C10: 10000 pF

2004-02-05



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Note 2: These are only typical curves and devices are not necessarily guaranteed at these curves.

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